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Substitute for form 1449A/PTO	Complete if Known		
	Application Number	10/054,451	
INFORMATION DISCLOSURE	Filing Date	01/18/2002	
STATEMENT BY APPLICANT	First Named Inventor	Petro Estakhri	
•	Group Art Unit	2188	
(use as many sheets as necessary)	Examiner Name	Namazi, Mehdi	

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ST	ATEMENT	BY APPLICA	First Named Inventor	Petro Estakhri		
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First Named Inventor Petro Estakhri

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Examiner	Date	,
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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